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6V / 500mA Low Drop-out Linear Regulator

JLR9193

Description

JLR9193 is a high-performance low drop-out linear regulator with input voltage range at $2 \sim 6V$ and output current up to 500mA. The drop-out voltage is very low at 210mV over output at 3.3V / 300mA. Despite of the already low quiescent current at 36μ A, the current consumed by the device can go further down to 0.01μ A once the device is "disabled". However, the device can resume quickly to full operation within 25µs from the rising edge of the enable signal.

Noise performance of the device is exceptional with PSRR = 75dB @ 1kHz. Output noise is as little as $45\mu V_{RMS}$. Coupled with outstanding line regulation at 0.03%, the device is a perfect fit to battery-operated wireless IoT terminals at the edge of access network. Operation integrity is further fortified with full suite of protection features (thermal shut-down, short-circuit handling, current limiting). The device delivers accurate (\pm 2%) output voltage at fixed levels: 1.8V, 2.8V, 3.3V.

JLR9193 is manufactured [halogen, lead, antimony] free and RoHS compliant. Packages offered are: DFN1010-4L, SOT-23-5L.

Applications

- Voltage regulation for loads sensitive to EMI hazards, and in systems where low on-demand power consumption is essential
- Mainboards in networked and battery-operated IoT Terminals
- Peripheral Board or Wireless Module inside Connected Devices, Wearables, Mobile Systems, Edge Terminals in Access Network

Features and Benefits

- Wide input voltage range at 2 ~ 6V and load current up to 500mA
- Drop-out voltage as low as 210mV given output at 3.3V / 300mA
- Low quiescent current at 36µA and shut-down current down to 0.01µA
- High accuracy (tolerance of V_{OUT} = \pm 2%) voltage output
- Exceptional PSRR performance of 75dB at 1kHz
- Outstanding line regulation of 0.03% at I_{LOAD} = 200mA and load regulation of 0.2% at I_{LOAD} = 1 ~ 300mA
- Stable operation with MLCC capacitors ($1.0\mu F / 1.0\mu F$) of X6S & X7R types close to input & output pins over wide range of T_A from -40°C to 85°C
- Fault protection for over-current, short-circuit, over-temperature
- Lead-free packages assembled with 'green' molding compound

Pin Assignment



Ordering Information



J333

Marking Information



II R9193S5-33

First Line: Marking (see Ordering Information)

Second Line: Date Code Y: Year of Molding W: Work-week of Molding I: Internal Code

DFN1010-4L





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Typical Application Circuit





Functional Blocks



Fig. 2: Diagram of Internal Functional Blocks



Absolute Maximum Ratings *1

Symbol	Parameter	Conditions	Rating	Unit
V _{IN}	Input Voltage at IN-pin	-	-0.3 ~ 6.5	V
TJ	Operating Junction Temperature	-	150	°C
T _{STG}	Storage Temperature Range	-	150	°C
TL	Lead Temperature	Soldering, 10s	300	°C
HBM	ESD (Human Body Model)	-	4	kV
CDM	ESD (Charged Device Model)	-	0.2	kV

Notes 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. While these are stress ratings only, functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" are not implied. Exposure to "Absolute Maximum Ratings" over extended periods may adversely affect the device reliability.

Recommended Operating Conditions

Symbol	Parameter	Conditions	Min.	Max.	Unit
V _{IN}	Input Voltage at IN-pin	IN to GND	2.0	6.0	V
I _{OUT}	Output Current	-	-	0.5	А
V _{EN}	Input Voltage at EN-pin	EN to GND	-	V _{IN} + 0.3	V
T _A	Operating Ambient Temperature	-	-40	85	°C



Electrical Characteristics

Test Conditions { $V_{IN} = V_{EN} = [V_{SET} + 1.0V]$ where $V_{SET} = V_{OUT} @ 1.8 / 2.8 / 3.3V$; $I_{OUT} = 1mA$; $C_{IN} = 1.0\mu F$ (ceramic); $C_{OUT} = 1.0\mu F$ (ceramic); $T_A = 25^{\circ}C$] are applicable to the following measurements unless otherwise specified.

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
V _{IN}	Operating Input Voltage	-	2.0	-	6.0	V
V _{OUT}	Output Voltage	$I_{OUT} = 1 m A; \ -40^{o}C \leq \ T_A \leq \ 85^{o}C$	V _{SET} * 0.98	V_{SET}	V _{SET} * 1.02	V
ILIMIT	Current Limit		-	500	-	mA
l _Q	Quiescent Current	$V_{EN} = V_{IN}$	-	50	-	μA
I _{SHDN}	Quiescent Current at Device-OFF	$V_{EN} = 0V$	-	0.01	1.00	μA
		I _{OUT} = 300mA; V _{SET} = 1.8V	-	380	520	
V _{DROP}	Drop-out Voltage	I _{OUT} = 300mA; V _{SET} = 2.8V	-	250	400	mV
		I _{OUT} = 300mA; V _{SET} = 3.3V	-	210	360	
Reg _{Load}	Load Regulation, $\Delta V_{OUT} / V_{OUT}$	$1mA \le I_{OUT} \le 300mA$	-	0.2	0.7	%
Reg _{Line}	Line Regulation, $\Delta V_{OUT} / V_{OUT}$	I_{OUT} = 10mA; $[V_{SET}$ + 1V] $\leq V_{IN} \leq 5.5V$	-	0.03	0.20	%
	Output Noise Voltage	I _{OUT} = 200mA; V _{OUT} = 1.8V		50	0 -	μV _{RMS}
		$10 \sim 100 \text{kHz}; C_{OUT} = 1 \mu \text{F}$	-	50		
۷N		I _{OUT} = 200mA; V _{OUT} = 2.8V		70		
		$10 \sim 100 \text{kHz}; C_{OUT} = 1 \mu \text{F}$	-	70	-	
DCDD	Power Supply Rejection Ratio	$I_{OUT} = 20mA; C_{OUT} = 1\mu F; f = 1kHz$	-	75	-	dB
		$I_{OUT} = 30mA; C_{OUT} = 1\mu F; f = 10kHz$	-	65	-	uВ
t _{ON}	Start Time	from $[V_{EN} = V_{IN}]$ to [90% of $V_{SET}]$	-	25	-	μS
V _{ENH}	EN Input Voltage for Logic 'H'	Device turned ON	1.5	-	-	V
V _{ENL}	EN Input Voltage for Logic 'L'	Device turned OFF	-	-	0.3	V
R _{EN-PD}	Pull-down Resistance at EN-pin		0.8	1	1.3	MΩ
T _{TSD}	Thermal Shut-down Threshold		-	155	-	°C
T _{TSD-Hys}	Thermal Shut-down Hysteresis		-	20	-	°C

Thermal Properties

Test Conditions: Device mounted on FR-4 substrate, 2-layer PCB, 2oz copper, with minimum recommended cooling pad to dissipate heat

Symbol	Parameter	Package	Rating	Unit
R _{eja}	Thermal Resistance (junction-to-ambient)	SOT-23-5L	200	⁰C/W
		DFN1010-4L	300	

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Performance Characteristics

Test Conditions [V_{IN} = 4.3V; I_{OUT} = 1mA; C_{IN} = 1.0 μ F (ceramic); C_{OUT} = 1.0 μ F (ceramic); T_A = 25°C] are applicable to the following measurements unless otherwise stated.

Graph 1: Output Voltage vs. Temperature



Graph 3: Input Current During Shut-down vs. Temperature







Graph 2: Quiescent Current vs. Temperature



Graph 4: Drop-out Voltage vs. Output Current



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Performance Characteristics (Continued)

Test Conditions [V_{IN} = 4.3V; I_{OUT} = 1mA; C_{IN} = 1.0 μ F (ceramic); C_{OUT} = 1.0 μ F (ceramic); T_A = 25°C] are applicable to the following measurements unless otherwise stated



Graph 6: Output Voltage vs. Output Current

Graph 8: Line Transient (V_{IN} = 4.3V → 6V; I_{OUT} = 10mA; t = 10µs)









Graph 9: Line Transient (V_{IN} = 6V → 4.3V; I_{OUT} = 10mA; t = 10µs)



Graph 11: Load Transient (I_{OUT} = 150mA → 1mA; t = 10µs)





Detailed Description of Device Operation

Overview

The JLR9193 is a high-performance linear regulator with input voltage up to 6.0V, and fixed output voltage levels (1.8V, 2.8V, 3.3V) at up to 500mA. While it operates on quiescent current as little as 36μ A, the PSRR performance stands at the exceptional 75dB over 10Hz ~ 100kHz, output voltage noise is as low as 45μ V_{RMS} at I_{OUT} = 200mA over the same frequency range. Should ultra-long battery time be required, the device can be disabled to keep the current consumption to as low as 0.01μ A. Response to transients occurred at the line input and the output load are swift at 0.03% and 0.2% accordingly.

Input & Output

In order to de-couple the noise and glitch present on the power line at the input of JLR9193 and the circuit board on which the device is adopted, input capacitor (C_{IN}) of ceramic type with value of 1µF as close as possible to the IN pin is recommended. Value of the C_{IN} shall fall within the range 0.47 ~ 4.70µF. Wide copper trace is required between the IN and the GND pins.

Output capacitor (C_{OUT}) of ceramic type with value of 1µF is recommended to be placed as close as possible to the OUT pin. While higher capacitance could potentially improve the load & line regulation performance and have the over-shoots and under-shoots minimized, care must be taken to ensure that the equivalent ESR do not adversely affect the high-frequency noise immunity as well as unexpected shift in phase response hence output stability. Values of the ESR and the C_{OUT} shall fall within the range 5 ~ 100m Ω and within the range 0.47 ~ 4.70µF respectively.

In order to minimize the temperature dependence of the application circuit, either X6S or X7R type is recommended for both the input and output capacitors.

Enable Feature

The device can be turned ON or OFF by driving the EN pin to either logic 'H' or logic 'L'. To ensure proper operation of the device, this pin must not be left unconnected. If the enable function is not used, this pin must be tied to the IN pin at all time such that the device remains at ON state all the time.

Current Protection

When the current appearing at the OUT pin goes up higher than the current limit designated for the device, or when the OUT & GND pins are shorted together, the built-in over-current and short-circuit protection shall be triggered. Upon the occurrence of such hazard, the output current (I_{OUT}) shall be limited by the internal logics to approximately 500mA. As a result, the device is protected from damage due to over-heat.

Thermal Protection & Power Dissipation

When the junction temperature (T_J) of the silicon die assembled inside the device goes up beyond the normality at close to 155°C, due either to excessive loading or short-circuit at the OUT pin, the built-in thermal shut-down protection shall be triggered. The on-die power MOSFET shall be turned OFF to prevent the device from electrical overload. At this time, the device shall operate on hiccup mode under which the output shall be enabled momentarily every so often. Should the over-temperature phenomenon persists due to the combination of power dissipation of the device, thermal resistance of the package, ambient temperature and the expiration of any circuit hazard, hiccup mode shall continue.

As soon as the abnormality disappears such that the junction temperature of the die comes down to approximately 130°C, the device shall resume its typical operation and drive the load connected to the OUT pin normally.





Package Outline (All measurements in mm)

Package Type: SOT-23-5L (J1)



SOT-23-5L (J1)				
Dimension	Min.	Max.		
A	1.05	1.25		
A1	0.00	0.10		
A2	1.05	1.15		
b	0.30	0.50		
с	0.10	0.20		
D	2.85	3.05		
E	1.50	1.70		
E1	2.65 2.95			
е	0.95 (BSC)			
e1	1.80	2.00		
L	0.30	0.60		
θ	0°	8°		
All measurements in "mm"				

Package Type: DFN1010-4L (J1)





DFN1010-4L (J1)				
Dimension	Min.	Тур.	Max.	
٨	0.45	0.50	0.55	
~	0.50	0.55	0.60	
A1	0.00	0.05		
A2		0.203 TIY		
b	0.17	0.22	0.27	
D	0.95	1.00	1.05	
D1	0.43	0.48	0.53	
E	0.95	1.00	1.05	
E1	0.43	0.48	0.53	
E2	0.065 TIY			
е	0.650 BSC			
К	0.200 BSC			
L	0.20	0.25	0.30	
All measurements in "mm"				



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